

Performance characteristics

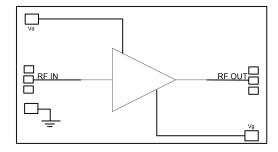
Frequency range: 0.1-18GHz
Small signal gain: 15.5dB
Noise figure: 1.5dB typ.

P-1dB: 17dBm

Power supply: +5V/35mA
Input/Output: 50Ohm
100% on-chip testing

Chip size: 0.99 x 0.95 x 0.1mm

Functional Block Diagram



Product Introduction

GLA-0018D is a broadband low-noise amplifier chip with a frequency range of 0.1-18GHz, a small signal gain of 15.5dB, a P-1dB output power of 17dBm, and a typical noise figure of 1.5dB in the band. The GLA-0018D is powered by a+5V,+0.5V power supply.

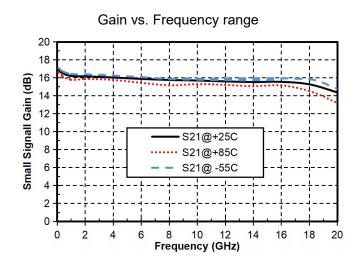
Use restriction parameters ¹		
Maximum leakage voltage	+7V	
Maximum input power	+20dBm	
Working temperature	-55 ~ +85°C	
Storage temperature	-65 ~ +150°C	

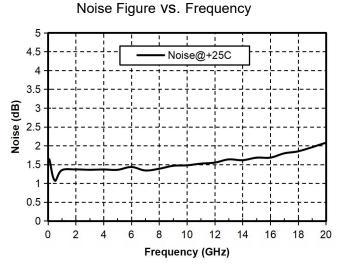
[1] Exceeding any of the above maximum limits may result in permanent damage.

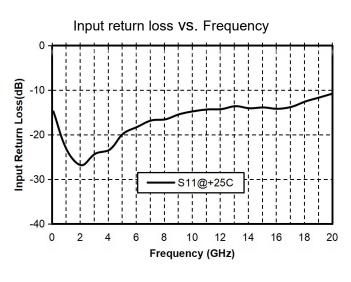
Electrical performance parameters(T _A = +25°C, Vd=+5V, Vg=+0.5V)				
Index	Minimum value	Typical value	Maximum value	Unit
Frequency range		0.1-18		GHz
Small signal gain	-	15.5	-	dB
Gain flatness		±0.8		dB
Noise figure	-	1.5	2.0	dB
P-1dB	-	17	-	dBm
Psat	-	18	-	dBm
Input return loss	-	17	-	dB
Output return Loss	-	18	-	dB
Static current		35		mA

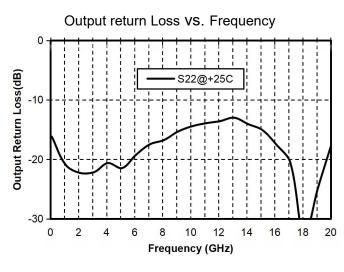


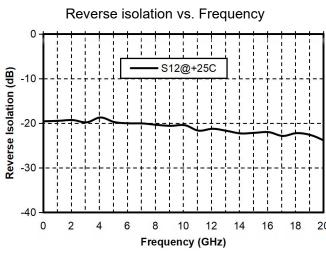
Main indicator testing curve

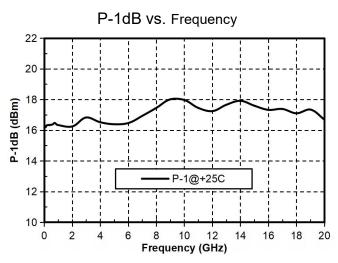






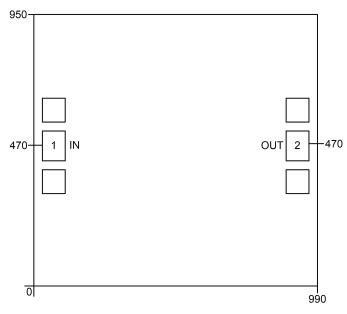








External structure²

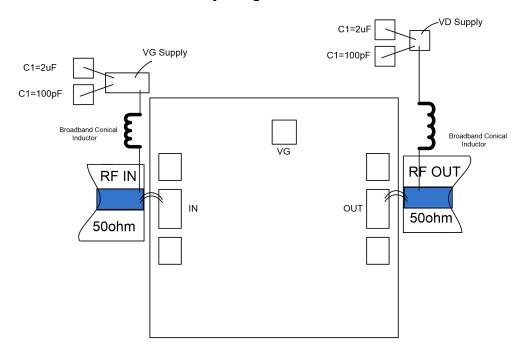


[2] The units in the figure are all millimeters, with a tolerance of ±100um.

Definition of bonding pressure point			
Bond point number	Functional symbols	Function Description	
1*	RF IN、Vg	RF signal input terminal; The amplifier gate bias requires external inductance and 100pF, 2uF bypass capacitors; Direct isolation capacitors need to be installed.	
2*	RF OUT、Vd	RF signal output terminal; The amplifier drain bias requires an external inductor and a 100pF, 2uF bypass capacitor; Direct isolation capacitors need to be installed.	
Chip bottom	GND	The bottom of the chip needs to be well grounded with RF and DC.	



Recommended assembly diagram



Notice

- The chip needs to be stored in a container with anti-static function and stored in a nitrogen environment.
- Attempting to clean the surface of bare chips using wet chemical methods is prohibited.
- Please strictly comply with ESD protection requirements to avoid static damage to bare chips.
- Routine operation: Please use precision pointed tweezers to remove the bare chip. During the operation, avoid tools or fingers touching the surface of the chip.
- Suggestion for mounting operation: Bare chip installation can use AuSn solder eutectic sintering or conductive adhesive bonding process. The installation surface must be clean and flat.
- Sintering process: It is recommended to use AuSn solder sheets with a gold tin ratio of 80/20. The working surface temperature reached 255 °C, and the tool (vacuum chuck) temperature reached 265 °C. When a high-temperature mixed gas (nitrogen to hydrogen ratio of 90/10) is blown onto the chip, the temperature at the top of the tool should be raised to 290 °C. Do not let the chip stay above 320 °C for more than 20 seconds. The friction time should not exceed 3 seconds.
- Bonding process: The amount of conductive adhesive applied should be as small as possible.
 After placing the chip in the installation position, the conductive adhesive can be vaguely visible around it. Please follow the information provided by the conductive adhesive manufacturer for curing conditions.
- Suggestion for bonding operation: Both spherical or wedge-shaped bonding should be used Φ
 0.025mm (1mil) gold wire. Thermal ultrasonic bonding temperature is 150 °C. The pressure of the

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spherical bonding cutter is 40-50GF, and the pressure of the wedge bonding cutter is 18-22GF. Use as little ultrasonic energy as possible. The bonding process starts at the pressing point on the chip and ends at the packaging (or substrate).

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